

# **PRODUCT BULLETIN # 20235**

Generic Copy

### Issue Date: 04-Oct-2013

<u>TITLE:</u> Datasheet Change of VIN shutdown current typical values and addition of OVP threshold min-max limits for NCP81038.

### PROPOSED FIRST SHIP DATE: 04-Jan-2014

#### AFFECTED CHANGE CATEGORY(S): Datasheet Revision

#### FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION:

Contact your local ON Semiconductor sales office or Mon Lingbaoan<<u>Mon.Lingbaoan@onsemi.com</u>>

#### **NOTIFICATION TYPE:**

ON Semiconductor considers this change approved unless specific conditions of acceptance are provided in writing. To do so, contact <quality@onsemi.com>.

#### **DESCRIPTION AND PURPOSE:**

First change is a correction on a typo on the datasheet for the typical value of the parameter VIN shutdown current. This is not a die change but only a typical value correction.

Second change is the addition of minimum and maximum limits for the OVP threshold parameter. This was previously a typical spec only.

#### Before:

Parameter	Test Conditions	Min	Тур	Max	Unit
Shutdown Current (Ivin_sd)	EN1, EN2, LDOEN, LDO2_EN = 0		5		uA
	EN1, EN2, LDOEN = 5 V, LDO2_EN = 5 V		100		uA
	EN1, EN2 = 0, LDOEN = 5V, LDO2_EN = 2.5 V		350		uA
	EN1, EN2 = 0, LDOEN = 5V, LDO2_EN = 0		300		uA

Parameter	Test Conditions	Min	Тур	Max	Unit
Output Overvoltage	After VCC POR, with		110		% Vref
Rising Threshold	respect to VFB		110		% viei

**ON Semiconductor** 



## PRODUCT BULLETIN # 20235

## After:

Parameter	Test Conditions	Min	Тур	Max	Unit
Shutdown Current	EN1, EN2, LDOEN,		5		uA
(lvin_sd)	$LDO2_EN = 0$				
	EN1, EN2, LDOEN = $5 V$ ,		1.15		mA
	LDO2_EN = 5 V				
	EN1, EN2 = 0, LDOEN =		1.57		mA
	5V, LDO2_EN = 2.5 V				
	EN1, EN2 = 0, LDOEN =		1.11		mA
	5V, LDO2_EN = 0				

Parameter	Test Conditions	Min	Тур	Max	Unit
Output Overvoltage	After VCC POR, with	106	110	118	% Vref
Rising Threshold	respect to VFB				

## List of affected General Parts:

NCP81038MNTWG NCP81038AMNTWG NCP5228MNTWG